

## Ultra Low Capacitance ESD Protection Array

### DESCRIPTION

GESD0512TL is an ultra-low capacitance ESD Protection Array with typical capacitance of 0.20pF (I/O to I/O) only, GESD0512TL is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4(±15KV air, ±8KV contact discharge), IEC61000-4-4 (electrical fast transient-EFT) (40A, 5/50ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

GESD0512TL uses small SOT-26 package. Each GESD0512TL device can protect two high-speed data lines and one Vcc line. The combined features of ultra-low capacitance, small size and high ESD robustness make GESD0512TL ideal for high-speed data ports and high-frequency lines (e.g., HDMI & DVI) applications. The low clamping voltage of the GESD0512TL guarantees a minimum stress on the protected IC.

### ORDERING INFORMATION

- ✧ Device: GESD0512TL
- ✧ Package: SOT-26
- ✧ Marking: UL26
- ✧ Material: Halogen free and RoHS compliant
- ✧ Packing: Tape & Reel
- ✧ Quantity per reel: 3,000pcs

### FEATURES

- ✧ Transient protection for high-speed data lines  
IEC 61000-4-2(ESD) ±20KV(Contact)  
IEC 61000-4-2(ESD) ±25KV(Air)
- ✧ Package optimized for high-speed lines
- ✧ Small package(2.9mm\*2.8mm\*1.1mm)
- ✧ Protects two data lines and one Vcc line
- ✧ Low capacitance: 0.20pF (I/O to I/O)
- ✧ Low leakage current
- ✧ Low clamping voltage
- ✧ Each I/O pin can withstand over 1000 ESD strikes for ±8KV contact discharge

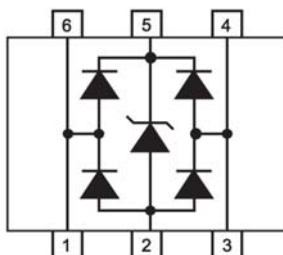
### MACHANICAL DATA

- ✧ SOT-26 package
- ✧ Flammability Rating: UL 94V-0
- ✧ Terminal: Matte tin plated.
- ✧ High temperature soldering guaranteed:  
✧ 260°C/10s
- ✧ Packaging: Tape and Reel
- ✧ Reel size: 7 inch

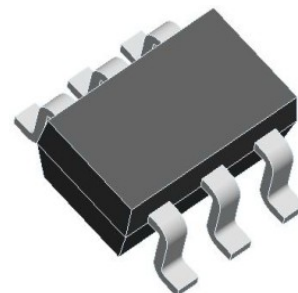
### APPLICATIONS

- ✧ Serial ATA
- ✧ MDDI Ports
- ✧ USB 2.0/3.0 Power and Data Line Protection
- ✧ Display Ports
- ✧ High Definition Multi-Media Interface (HDMI)
- ✧ Digital Visual Interface (DVI)

### PIN CONFIGURATION



### PACKAGE OUTLINE



### ABSOLUTE MAXIMUM RATING

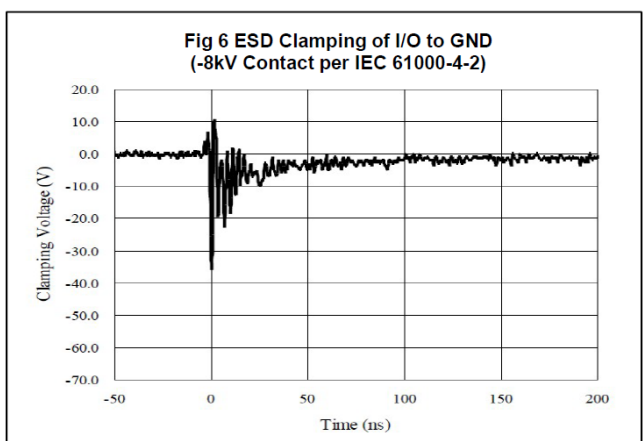
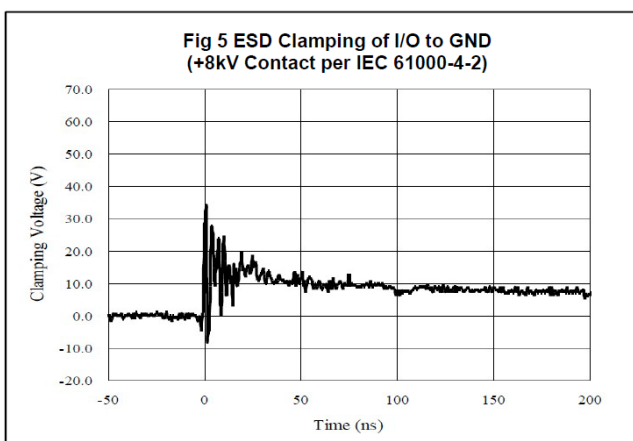
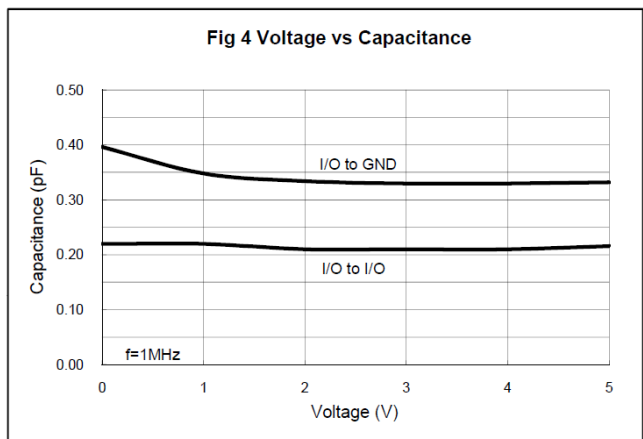
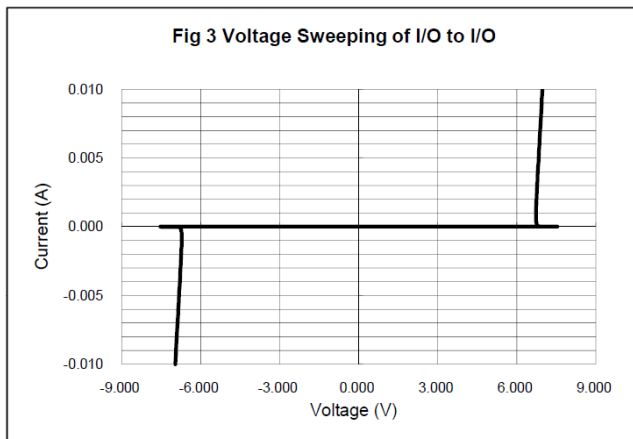
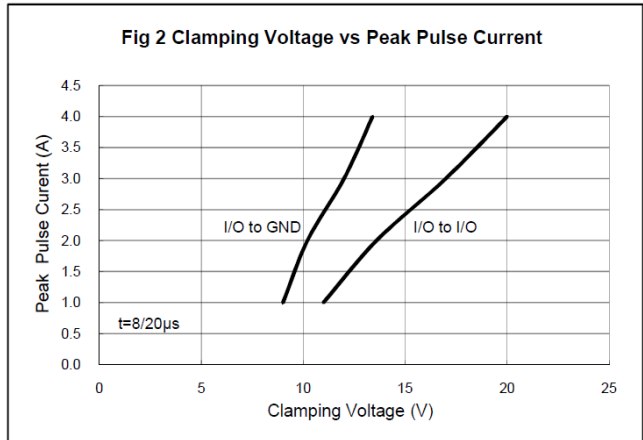
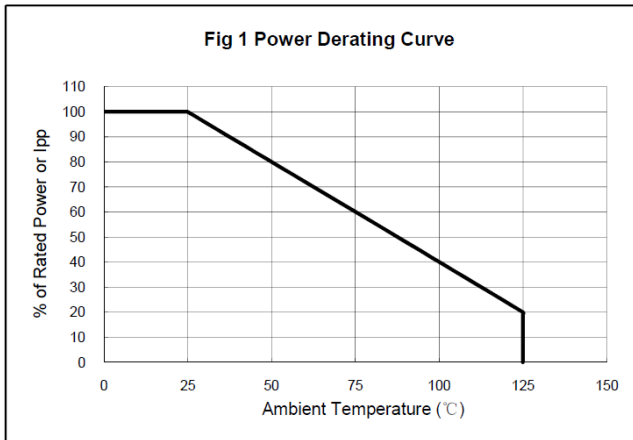
Symbol	Parameter	Value	Units
P <sub>PP</sub>	Peak Pulse Power (8/20μs)	60	W
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±20 ±25	kV
T <sub>OPT</sub>	Operating Temperature	-55/+125	°C
T <sub>STG</sub>	Storage Temperature	-55/+150	°C

### ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C)

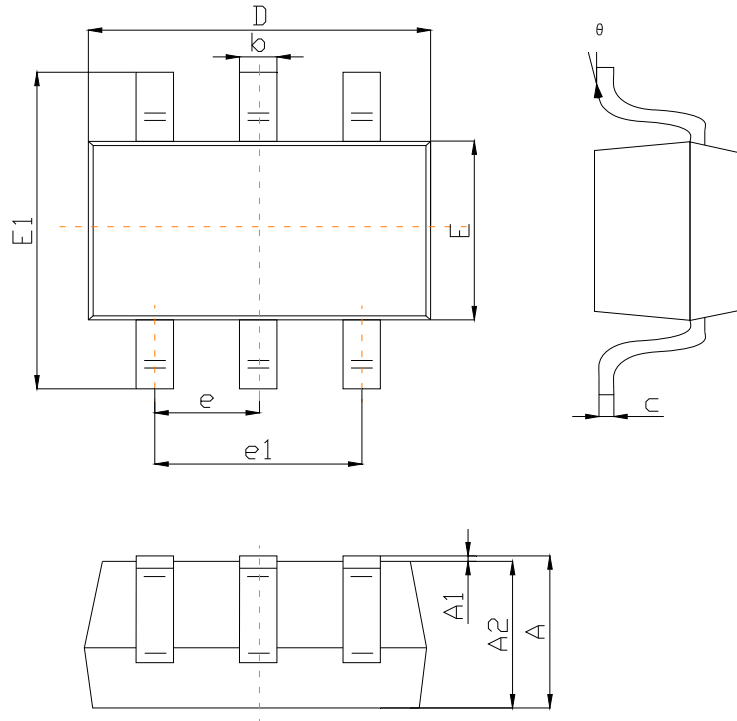
Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V <sub>RWM</sub>	Reverse Working Voltage	Any I/O pin to GND			5.0	V
V <sub>BR</sub>	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA Any I/O pin to GND	6.0		9.0	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 5V Any I/O pin to GND			1.0	μA
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 1A, t <sub>p</sub> = 8/20μs Any I/O pin to GND			10	V
		I <sub>PP</sub> = 4A, t <sub>p</sub> = 8/20μs Any I/O pin to GND			15	V
		I <sub>PP</sub> = 8A, t <sub>p</sub> = 8/20μs V <sub>CC</sub> pin to GND			15	V
C <sub>ESD</sub>	Parasitic Capacitance	V <sub>R</sub> = 0V, f = 1MHz Between I/O and I/O		0.20	0.30	pF
		V <sub>R</sub> = 0V, f = 1MHz Between I/O and GND		0.45	0.50	pF
		V <sub>R</sub> = 0V, f = 1MHz Between V <sub>CC</sub> and GND		0.80		pF

Note: I/O Pins are Pin 1,3,4,6. Pin 5 is V<sub>CC</sub>. Pin 2 is GND.

### ELECTRICAL CHARACTERISTICS CURVE



### SOT-26 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100		0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0,950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
	0°	8°	0°	8°